## 1.2 Features

This section summarizes features of the 603e's implementation of the PowerPC architecture. Major features of the 603e are as follows:

- · High-performance, superscalar microprocessor
  - As many as three instructions issued and retired per clock
  - As many as five instructions in execution per clock
  - Single-cycle execution for most instructions
  - Pipelined FPU for all single-precision and most double-precision operations
- Five independent execution units and two register files
  - BPU featuring static branch prediction
  - A 32-bit IU
  - Fully IEEE 754-compliant FPU for both single- and double-precision operations
  - LSU for data transfer between data cache and GPRs and FPRs
  - SRU that executes condition register (CR), special-purpose register (SPR) instructions, and integer add/compare instructions
  - Thirty-two GPRs for integer operands
  - Thirty-two FPRs for single- or double-precision operands
- · High instruction and data throughput
  - Zero-cycle branch capability (branch folding)
  - Programmable static branch prediction on unresolved conditional branches
  - Instruction fetch unit capable of fetching two instructions per clock from the instruction cache
  - A six-entry instruction queue that provides lookahead capability
  - Independent pipelines with feed-forwarding that reduces data dependencies in hardware
  - 16-Kbyte data cache—four-way set-associative, physically addressed; LRU replacement algorithm
  - 16-Kbyte instruction cache—four-way set-associative, physically addressed; LRU replacement algorithm
  - Cache write-back or write-through operation programmable on a per page or per block basis
  - BPU that performs CR lookahead operations
  - Address translation facilities for 4-Kbyte page size, variable block size, and 256-Mbyte segment size
  - A 64-entry, two-way set-associative ITLB
  - A 64-entry, two-way set-associative DTLB
  - Four-entry data and instruction BAT arrays providing 128-Kbyte to 256-Mbyte blocks
  - Software table search operations and updates supported through fast trap mechanism
  - 52-bit virtual address; 32-bit physical address
- Facilities for enhanced system performance
  - A 32- or 64-bit split-transaction external data bus with burst transfers
  - Support for one-level address pipelining and out-of-order bus transactions

- · Integrated power management
  - Low-power 2.5/3.3-volt design
  - Internal processor/bus clock multiplier that provides 2/1, 2.5/1, 3/1, 3.5/1, 4/1, 4.5/1, 5/1, 5.5/1, and 6/1 ratios
  - Three power saving modes: doze, nap, and sleep
  - Automatic dynamic power reduction when internal functional units are idle
- In-system testability and debugging features through JTAG boundary-scan capability

## 1.3 General Parameters

The following list provides a summary of the general parameters of the PID7v-603e:

Technology

0.35 m CMOS, five-layer metal

Die size

10.5 mm x 7.5 mm (79 mm<sup>2</sup>)

Transistor count

2.6 million

Logic design

Fully-static

Package

Surface mount 240-pin ceramic quad flat pack (CQFP)

or 255 ceramic ball grid array (BGA)

Core power supply

2.5 5% V dc

I/O power supply

3.3 5% V dc

## 1.4 Electrical and Thermal Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the PID7v-603e.

#### 1.4.1 DC Electrical Characteristics

The tables in this section describe the PID7v-603e DC electrical characteristics. Table 1 provides the absolute maximum ratings.

Table 2 provides the recommended operating conditions for the PID7v-603e.

Table 1. Absolute Maximum Ratings

Characteristic	Symbol	Value	Unit
Core supply voltage	Vdd	-0.3 to 2.75	V
PLL supply voltage	AVdd	-0.3 to 2.75	V
I/O supply voltage	OVdd	-0.3 to 3.6	V
Input voltage	V <sub>in</sub>	-0.3 to 5.5	V
Storage temperature range	T <sub>stg</sub>	-55 to 150	С

#### Notes:

- Functional and tested operating conditions are given in Table 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
- 2. Caution: Vin must not exceed OVdd by more than 2.5 V at any time, including during power-on reset.
- 3. Caution: OVdd must not exceed Vdd/AVdd by more than 1.2 V at any time, including during power-on reset.
- 4. Caution: Vdd/AVdd must not exceed OVdd by more than 0.4 V at any time, including during power-on reset.

**Table 2. Recommended Operating Conditions** 

Characteristic	Symbol	Value	Unit	
Core supply voltage	Vdd	2.375 to 2,625	V	
PLL supply voltage	AVdd	2.375 to 2.625	V	
I/O supply voltage	OVdd	3.135 to 3.465	V	
Input voltage	V <sub>in</sub>	GND to 5.5	V	
Junction temperature	Tj	0 to 105	С	

Note: These are the recommended and tested operating conditions. Proper device operation outside of these conditions is not guaranteed.

Table 3 provides the package thermal characteristics for the PID7v-603e.

**Table 3. Thermal Characteristics** 

Characteristic	Symbol	Value	Rating
Motorola wire-bond CQFP package thermal resistance, junction-to-case (typical)	θ <sub>JC</sub>	2.2	C/W
IBM C4-CQFP package thermal resistance, junction-to-case	θJC	3.6	C/W
BGA package thermal resistance, junction-to-top-of-die	θ <sub>JC</sub>	0.03	C/W

Note: Refer to Section 1.8, "System Design Information," for more details about thermal management.

Table 4 provides the DC electrical characteristics for the PID7v-603e.

### **Table 4. DC Electrical Specifications**

Vdd = AVdd = 2.5 5% V dc OVdd = 3.3 5% V dc GND = 0 V dc, 0 Tj 105 C

Characteristic	Symbol	Min	Max	Unit	Note s
Input high voltage (all inputs except SYSCLK)	V <sub>IH</sub>	2.0	5.5	٧	
Input low voltage (all inputs except SYSCLK)	V <sub>IL</sub>	GND	0.8	٧	
SYSCLK input high voltage	CVIH	2.4	5.5	٧	
SYSCLK input low voltage	CVIL	GND	0.4	V	-
Input leakage current, V <sub>in</sub> = 3.465 V	l <sub>in</sub>	_	30	Α	1,2
V <sub>in</sub> = 5.5 V	lin	-	300	Α	1,2
Hi-Z (off-state) leakage current, V <sub>in</sub> = 3.465 V	I <sub>TSI</sub>		30	A	1,2
V <sub>in</sub> = 5.5 V	I <sub>TSI</sub>		300	Α	1,2
Output high voltage, I <sub>OH</sub> = -7 mA	V <sub>OH</sub>	2.4		V	
Output low voltage, I <sub>OL</sub> = 7 mA	V <sub>OL</sub>		0.4	V	
Capacitance, $V_{in}$ = 0 V, f = 1 MHz (excludes $\overline{TS}$ , $\overline{ABB}$ , $\overline{DBB}$ , and $\overline{ARTRY}$ )	C <sub>in</sub>		10.0	pF	3
Capacitance, $V_{in} = 0 \text{ V, } f = 1 \text{ MHz (for } \overline{TS}, \overline{ABB}, \overline{DBB}, \text{ and } \overline{ARTRY})$	C <sub>in</sub>	_	15.0	pF	3

- 1. Excludes test signals (LSSD\_MODE, L1\_TSTCLK, L2\_TSTCLK, and JTAG signals).
- 2. The leakage is measured for nominal OVdd and Vdd or both OVdd and Vdd must vary in the same direction (for example, both OVdd and Vdd vary by either +5% or -5%).
- 3. Capacitance is periodically sampled rather than 100% tested.

Table 5 provides the power consumption for the PID7v-603e.

**Table 5. Power Consumption** 

			Processor (C	PU) Frequenc	У		
	160 MHz	166 MHz	180 MHz	200 MHz	220, 225 MHz	233, 240 MHz	Unit
Full-On Mode (D	PM Enabled)		<del>                                     </del>		<u> </u>		
Typical	2.9	3.0	3.5	4.0	4.4	4.8	W
Maximum	3.8	4.0	4.5	5.0	5.5	6.0	w
Doze Mode					<del></del>	·	
Typical	1.2	1.2	1.4	1.5	1.7	1.8	w
Nap Mode							•
Typical	75	80	100	120	132	140	mW
Sleep Mode							
Typical	65	70	80	100	110	120	mW
Sleep Mode—PL	L Disabled	1					
Typical	60	60	60	60	60	60	mW
Sleep Mode—PL	L and SYSCLK D	isabled	nalises and an area and an area and				
Maximum	60	60	60	60	60	60	mW

#### Notes:

- 1.These values apply for all valid PLL\_CFG[0-3] settings and do not include output driver power (OVdd) or analog supply power (AVdd). OVdd power is system dependent but is typically 10% of Vdd. Worst-case AVdd = 15 mW.
- 2. Typical power is an average value measured at Vdd = AVdd = 2.5 V, OVdd = 3.3V, in a system executing typical applications and benchmark sequences.
- 3. Maximum power is measured at 2.625 V using a worst-case instruction mix.

### 1.4.2 AC Electrical Characteristics

This section provides the AC electrical characteristics for the PID7v-603e. These specifications are for 160, 166, 180, 200, 225, 233, and 240 MHz processor core frequencies. The processor core frequency is determined by the bus (SYSCLK) frequency and the settings of the PLL\_CFG[0-3] signals. All timings are specified respective to the rising edge of SYSCLK. PLL\_CFG signals should be set prior to power up and not altered afterwards.

### 1.4.2.1 Clock AC Specifications

Table 6 provides the clock AC timing specifications as defined in Figure 1. After fabrication, parts are sorted by maximum processor core frequency as shown in Section 1.4.2.1, "Clock AC Specifications" and tested for conformance to the AC specifications for that frequency. Parts are sold by maximum processor core frequency; see Section 1.9, "Ordering Information."

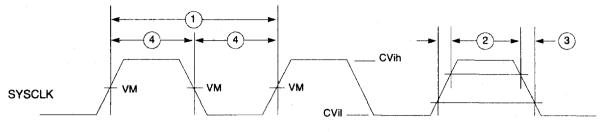
### **Table 6. Clock AC Timing Specifications**

Vdd = AVdd = 2.5 5% V dc OVdd = 3.3 5% V dc GND = 0 V dc, 0 Ti 105 C

Num	Characteristic	160	MHz	166	MHz	180	MHz	200	MHz		, 225 Hz	1	, 240 IHz	Unit	Note
Additional and Physical Confession of		Min	Мах	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		S
	Processor frequency	125	160	125	167	125	180	125	200	125	220, 225	125	233, 240	MHz	1
	VCO frequency	250	320	250	333	250	360	250	400	250	440, 450	250	466, 480	MHz	1
<del>d- w - the</del> e summer december	SYSCLK frequency	25	66.67	25	66.67	25	66.67	25	66.67	25	75	25	75	MHz	1
1	SYSCLK cycle time	15	40.0	15	40.0	15	40.0	15	40.0	13.3	40.0	13.3	40.0	ns	
2,3	SYSCLK rise and fall time		2.0		2.0		2.0		2.0	-	2.0		2.0	ns	2
4	SYSCLK duty cycle measured at 1.4 V	40.0	60.0	40.0	60.0	40.0	60.0	40.0	60.0	40.0	60.0	40.0	60.0	%	3
	SYSCLK jitter		150		150		150		150		150	_	150	ps	4
	603e internal PLL-relock time	_	100		100		100		100		100	_	100	μs	3,5

- 1. Caution: The SYSCLK frequency and PLL\_CFG[0-3] settings must be chosen such that the resulting SYSCLK (bus) frequency, CPU (core) frequency, and PLL (VCO) frequency do not exceed their respective maximum or minimum operating frequencies. Refer to the PLL\_CFG[0-3] signal description in Section 1.8, "System Design Information," for valid PLL\_CFG[0-3] settings.
- 2. Rise and fall times for the SYSCLK input are measured from 0.4 V to 2.4 V.
- 3. Timing is guaranteed by design and characterization, and is not tested.
- 4. Cycle-to-cycle jitter, and is guaranteed by design. The total input jitter (short term and long term combined) must be under 150 ps
- 5. Relock timing is guaranteed by design and characterization, and is not tested. PLL-relock time is the maximum time required for PLL lock after a stable Vdd, OVdd, AVdd, and SYSCLK are reached during the power-on reset sequence. This specification also applies when the PLL has been disabled and subsequently re-enabled during sleep mode. Also note that HRESET must be held asserted for a minimum of 255 bus clocks after the PLL-relock time (100 μs) during the power-on reset sequence.

Figure 1 provides the SYSCLK input timing diagram.



VM = Midpoint Voltage (1.4 V)

Figure 1. SYSCLK Input Timing Diagram

## 1.4.2.2 Input AC Specifications

Table 7 provides the input AC timing specifications for the PID7v-603e as defined in Figure 2 and Figure 3.

### Table 7. Input AC Timing Specifications<sup>1</sup>

 $Vdd = AVdd = 2.5 ext{ 5\% V dc OVdd} = 3.3 ext{ 5\% V dc GND} = 0 ext{ V dc, 0 } Tj ext{ 105 C}$ 

Num	Characteristic	1	56, 180, MHz	1 5 1	25, 233, MHz	Unit	Notes	
		Min	Max	Min	Max			
10a	Address/data/transfer attribute inputs valid to SYSCLK (input setup)	2.5		2.5		ns	2	
10b	All other inputs valid to SYSCLK (input setup)	4.0		3.5		ns	3	
10c	Mode select inputs valid to HRESET (input setup) (for DRTRY, QACK and TLBISYNC)	8		8		tsyscik	4, 5, 6, 7	
11a	SYSCLK to address/data/transfer attribute inputs invalid (input hold)	1.0		1.0		ns	2	

### Table 7. Input AC Timing Specifications<sup>1</sup> (Continued)

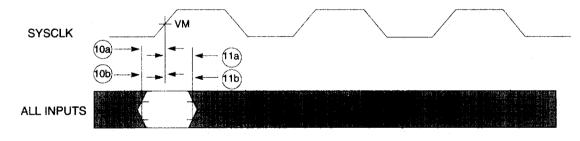
Vdd = AVdd = 2.5 5% V dc OVdd = 3.3 5% V dc GND = 0 V dc, 0 Tj 105 C

Num	Characteristic						Notes	
		Min	Max	Min	Max			
11b	SYSCLK to all other inputs invalid (input hold)	1.0	-	1.0		ns	3	
11c	HRESET to mode select inputs invalid (input hold) (for DRTRY, QACK, and TLBISYNC)	0		0		ns	4, 6, 7	

#### Notes:

- 1. Input specifications are measured from the TTL level (0.8 or 2.0 V) of the signal in question to the 1.4 V of the rising edge of the input SYSCLK. Input and output timings are measured at the pin.
- 2. Address/data/transfer attribute input signals are composed of the following—A[0-31], AP[0-3], TT[0-4], TC[0-1], TBST, TStZ[0-2], GBL, DH[0-31], DL[0-31], DP[0-7].
- 3. All other input signals are composed of the following—TS, ABB, DBB, ARTRY, BG, AACK, DBG, DBWO, TA, DRTRY, TEA, DBDIS, HRESET, SRESET, INT, SMI, MCP, TBEN, QACK, TLBISYNC.
- 4. The setup and hold time is with respect to the rising edge of HRESET (see Figure 3).
- 5. t<sub>sysclk</sub> is the period of the external clock (SYSCLK) in nanoseconds (ns). The numbers given in the table must be multiplied by the period of SYSCLK to compute the actual time duration (in nanoseconds) of the parameter in question.
- 6. These values are guaranteed by design, and are not tested.
- 7. This specification is for configuration mode only. Also note that HRESET must be held asserted for a minimum of 255 bus clocks after the PLL-relock time during the power-on reset sequence.

Figure 2 provides the input timing diagram for the PID7v-603e.



VM = Midpoint Voltage (1.4 V)

Figure 2. Input Timing Diagram

Figure 3 provides the mode select input timing diagram for the PID7v-603e.

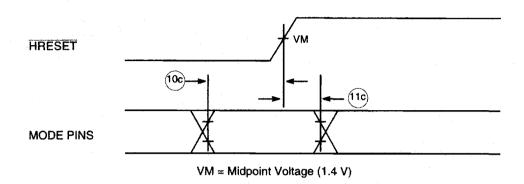


Figure 3. Mode Select Input Timing Diagram

## 1.4.2.3 Output AC Specifications

Table 8 provides the output AC timing specifications for the PID7v-603e as defined in Figure 4.

## Table 8. Output AC Timing Specifications<sup>1</sup>

 $Vdd = AVdd = 2.5 \pm 5\% \ V \ dc, \ OVdd = 3.3 \quad 5\%, \ GND = 0 \ V \ dc, \ 0 \quad T_{j} \quad 105 \ \mathcal{L}_{L} = 50 \ pF \ (unless \ otherwise \ noted)$ 

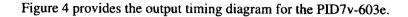
Num	Characteristic		66, 180, MHz		25, 233, MHz	Unit	Notes
		Min	Max	Min	Max		
12	SYSCLK to output driven (output enable time)	1.0		1.0		ns	
13a	SYSCLK to output valid (5.5 V to 0.8 V—TS, ABB, ARTRY, DBB)		9.0		9.0	ns	3
13b	SYSCLK to output valid (TS, ABB, ARTRY, DBB)		8.0	_	8.0	ns	5
14a	SYSCLK to output valid (5.5 V to 0.8 V—all except TS, ABB, ARTRY, DBB)		11.0		11.0	ns	3
14b	SYSCLK to output valid (all except TS, ABB, ARTRY, DBB)		9.0		9.0	ns	5
15	SYSCLK to output invalid (output hold)	1.0		1.0		ns	2
16	SYSCLK to output high impedance (all except ARTRY, ABB, DBB)		8.5		8.0	ns	
17	SYSCLK to ABB, DBB, high impedance after precharge		1.0	_	1.0	t <sub>sysclk</sub>	4, 6
18	SYSCLK to ARTRY high impedance before precharge		8.0	_	7.5	ns	

## Table 8. Output AC Timing Specifications<sup>1</sup> (Continued)

Vdd = AVdd =  $2.5 \pm 5\%$  V dc, OVdd =  $3.3 \pm 5\%$ , GND = 0 V dc 0 Tj 105, CC<sub>L</sub> = 50 pF (unless otherwise noted)

Num	Characteristic	160, 166, 180, 200 MHz		220, 22 240		Unit	Notes
		Min	Max	Min	Max		
19	SYSCLK to ARTRY precharge enable	0.2 * t <sub>sysclk</sub> + 1.0		0.2 * t <sub>syscik</sub> + 1.0		ns	2, 4, 7
20	Maximum delay to ARTRY precharge		1.0		1.0	t <sub>syscik</sub>	4, 7
21	SYSCLK to ARTRY high impedance after precharge		2.0		2.0	t <sub>sysclk</sub>	5,7

- 1. All output specifications are measured from the 1.4 V of the rising edge of SYSCLK to the TTL level (0.8 V or 2.0 V) of the signal in question. Both input and output timings are measured at the pin (see Figure 4).
- 2. This minimum parameter assumes C<sub>L</sub> = 0 pF.
- 3. SYSCLK to output valid (5.5 V to 0.8 V) includes the extra delay associated with discharging the external voltage from 5.5 V to 0.8 V instead of from Vdd to 0.8 V (5-V CMOS levels instead of 3.3-V CMOS levels).
- 4. t<sub>sysclk</sub> is the period of the external bus clock (SYSCLK) in nanoseconds (ns). The numbers given in the table must be multiplied by the period of SYSCLK to compute the actual time duration (in nanoseconds) of the parameter in question.
- 5. Output signal transitions from GND to 2.0 V or Vdd to 0.8 V.
- 6. Nominal precharge width for ABB and DBB is 0.5 t<sub>sysolk</sub>.
- 7. Nominal precharge width for ARTRY is 1.0 t<sub>sysclk</sub>.



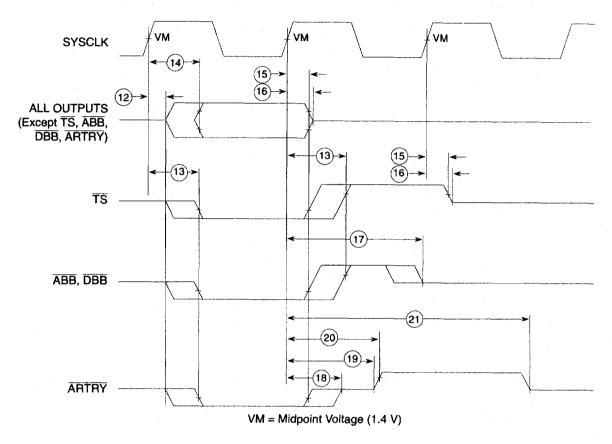


Figure 4. Output Timing Diagram

## 1.4.3 JTAG AC Timing Specifications

Table 9 provides the JTAG AC timing specifications as defined in Figure 5, Figure 6, Figure 7 and Figure 8.

#### **Table 9. JTAG AC Timing Specifications**

 $Vdd = AVdd = 2.5 \quad 5\% \ V \ dc \ OVdd = 3.3 \quad 5\%, \ GND = 0 \ V \ dc \ 0 \quad Tj \quad 105 \ CC_L = 50 \ pF$ 

Num	Characteristic	Min	Max	Unit	Notes
	TCK frequency of operation	0	16	MHz	
1	TCK cycle time	62.5		ns	
2	TCK clock pulse width measured at 1.4 V	25		ns	
3	TCK rise and fall times	0	3	ns	
4	TRST setup time to TCK rising edge	13		ns	1
5	TRST assert time	40	_	ns	
6	Boundary scan input data setup time	6		ns	2
7	Boundary scan input data hold time	27	_	ns	2
8	TCK to output data valid	4	25	ns	3
9	TCK to output high impedance	3	24	ns	3
10	TMS, TDI data setup time	0	_	ns	
11	TMS, TDI data hold time	25		ns	
12	TCK to TDO data valid	4	24	ns	
13	TCK to TDO high impedance	3	15	ns	
					<u> </u>

- 1. TRST is an asynchronous signal. The setup time is for test purposes only.
- 2. Non-test signal input timing with respect to TCK.
- 3. Non-test signal output timing with respect to TCK.

Figure 5 provides the JTAG clock input timing diagram.

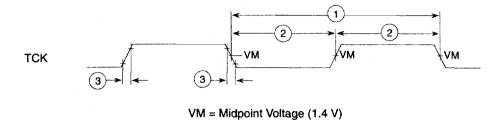


Figure 5. JTAG Clock Input Timing Diagram

Figure 6 provides the TRST timing diagram.

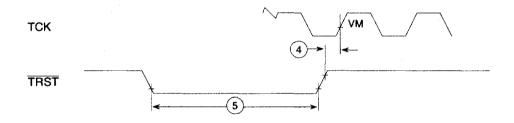


Figure 6. TRST Timing Diagram

Figure 7 provides the boundary-scan timing diagram.

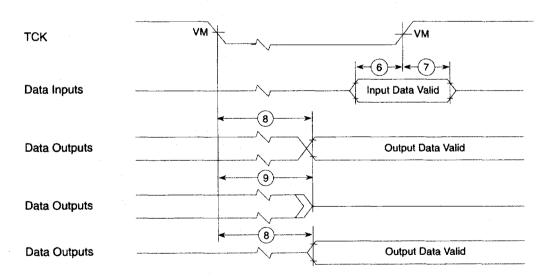


Figure 7. Boundary-Scan Timing Diagram

Figure 8 provides the test access port timing diagram.

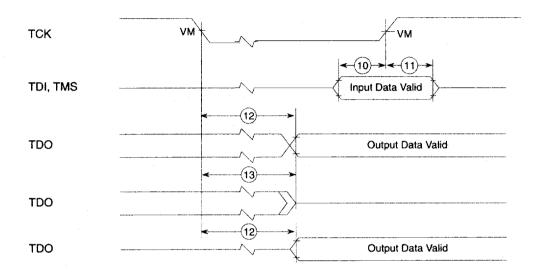


Figure 8. Test Access Port Timing Diagram

# 1.5 PowerPC 603e Microprocessor Pin Assignments

The following sections contain the pinout diagrams for the 603e. Note that the 603e is offered in both ceramic quad flat pack (CQFP) and ceramic ball grid array (BGA) packages.

## 1.5.1 Pinout Diagram for the CQFP Package

Figure 9 contains the CQFP pin assignments for the 603e.

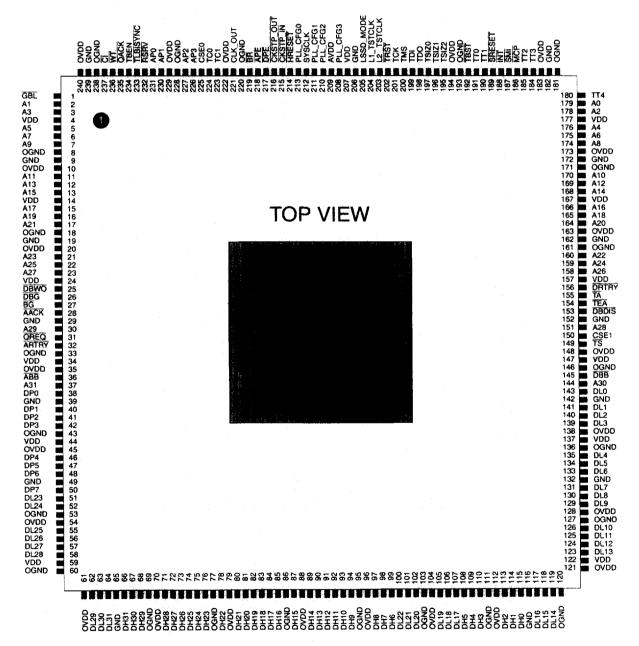
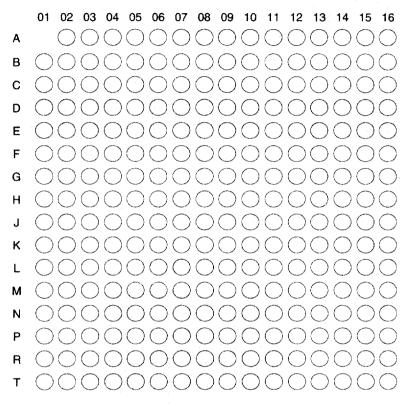


Figure 9. Pinout of the CQFP Package

## 1.5.2 Pinout Diagram for the BGA Package

Figure 10 (in part A) shows the pinout of the BGA package as viewed from the top surface. Part B shows the side profile of the BGA package to indicate the direction of the top surface view.

#### Part A



Not to Scale

#### Part B

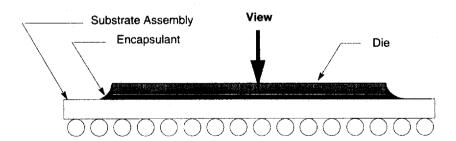


Figure 10. Pinout of the BGA Package as Viewed from the Top Surface